SLLS171G - OCTOBER 1993 - REVISED MARCH2009

- Meets or Exceeds the EIA Standards RS-422-A, RS-423-A, RS-485, and CCITT Recommendation V.11
- Designed to Operate With Pulse Durations as Short as 20 ns
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- Input Sensitivity . . . ±200 mV
- Low-Power Consumption . . . 20 mA Max
- Open-Circuit Fail-Safe Design
- Common-Mode Input Voltage Range of -7 V to 12 V
- Pin Compatible With SN75175 and LTC489

#### description

The SN65LBC175 and SN75LBC175 are monolithic, quadruple, differential line receivers with 3-state outputs designed to meet the requirements of the EIA standards RS-422-A, RS-423-A, RS-485, and CCITT Recommendation V.11. The devices are optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. The receivers are enabled in pairs, with an active-high enable input. Each differential receiver input features high impedance, hysteresis for increased noise immunity, and sensitivity of ±200 mV over a common-mode input voltage range of 12 V to −7 V. The fail-safe design ensures that when the inputs are open-circuited, the outputs are always high. Both devices are designed using the TI proprietary LinBiCMOS<sup>™</sup> technology allowing low power consumption, high switching speeds, and robustness.

These devices offer optimum performance when used with the SN75LBC172 or SN75LBC174 quadruple line drivers. The SN65LBC175 is available in the 16-pin DIP (N), small-outline package (D), and the wide small-outline package (DW). The SN75LBC175 is available in the 16-pin DIP (N) and the small-outline package (D).

The SN65LBC175 is characterized over the industrial temperature range of  $-40^{\circ}$ C to  $85^{\circ}$ C. The SN75LBC175 is characterized for operation over the commercial temperature range of  $0^{\circ}$ C to  $70^{\circ}$ C.

BAOKAOE	TEMPERATURE RANGE						
PACKAGE	0°C to 70°C	–40°C to 85°C					
SOIC	SN75LBC175D	SN65LBC175D					
Wide SOIC	—	SN65LBC175DW					
PDIP	SN75LBC175N	SN65LBC175N					

AVAILABLE OPTIONS



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



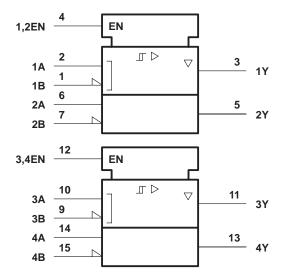
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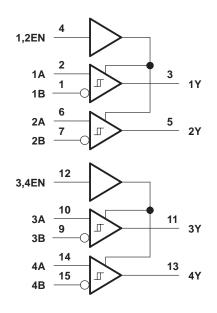
D, DW, OR N PACKAGE (TOP VIEW)						
			L			
1B [	1	16	] V <sub>CC</sub> ] 4B			
1A [	2	15	] 4B			
1Y 🛛	3	14	] 4A			
1,2EN	4	13	] 4Y			
2Y [	5	12	] 3,4EN			
2A 🛛	6	11	] 3Y			
2B 🛛	7	10	] 3A			
GND [	8	9	] 3B			

SLLS171G – OCTOBER 1993 – REVISED MARCH2009

### logic symbol<sup>†</sup>



logic diagram (positive logic)



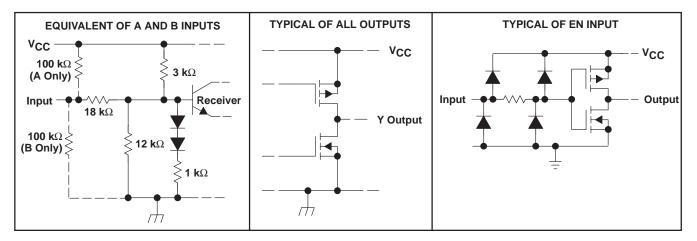
<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

FUNCTION TABLE
(each receiver)

(edch receiver)								
DIFFERENTIAL INPUTS A-B	ENABLE	OUTPUT Y						
$V_{ID} \ge 0.2 V$	Н	Н						
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	Н	?						
$V_{ID} \le -0.2 V$	Н	L						
Х	L	Z						
Open circuit	Н	Н						

H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

### schematics of inputs and outputs





SLLS171G - OCTOBER 1993 - REVISED MARCH2009

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub> (see Note 1)	±25 V
Differential input voltage, V <sub>ID</sub> (see Note 2)	
Continuous total dissipation	00
Operating free-air temperature range, T <sub>A</sub> : SN65LBC175	1 3
SN75LBC175	0°C to 70°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Electrostatic Discharge (ESD): Human Body Model (HBM)	1 kV
Machine Model (MM)	
Charged Device Model (CDM)	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to GND.

2. Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.

# DISSIPATION RATING TABLE

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
D	1100 mW	8.7 mW/°C	709 mW	578 mW
DW	1200 mW	9.6 mW/°C	770 mW	625 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW

### recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>				5	5.25	V
Common-mode input voltage, VIC			-7		12	V
Differential input voltage, VID					±6	V
High-level input voltage, VIH	Ebligante					V
Low-level input voltage, VIL	EN Inputs	EN inputs				V
High-level output current, I <sub>OH</sub>					-8	mA
Low-level output current, IOL					8	mA
Operating free-air temperature, T <sub>A</sub>	SN65LBC1	75	-40		85	° <b>0</b>
	SN75LBC1	75	0		70	°C



SLLS171G – OCTOBER 1993 – REVISED MARCH2009

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TEST CONDITIONS			MIN	TYP†	MAX	UNIT
$V_{IT+}$	Positive-going input three	shold voltage	$I_{O} = -8 \text{ mA}$	$I_{O} = -8 \text{ mA}$				0.2	V
VIT-	Negative-going input three	eshold voltage	IO = 8 mA			-0.2			V
V <sub>hys</sub>	Hysteresis voltage (VIT.	+ - VIT_)					45		mV
VIK	Enable input clamp volta	ge	lı = – 18 mA				-0.9	-1.5	V
۷он	High-level output voltage	•	V <sub>ID</sub> = 200 mV,	IOH = -8 m	A	3.5	4.5		V
VOL	Low-level output voltage		$V_{ID} = -200 \text{ mV},$	I <sub>OL</sub> = 8 mA			0.3	0.5	V
I <sub>OZ</sub>	High-impedance-state or	utput current	$V_{O} = 0 V$ to $V_{CC}$					±20	μA
			V <sub>IH</sub> = 12 V,	V <sub>CC</sub> = 5 V,	Other inputs at 0 V		0.7	1	
			V <sub>IH</sub> = 12 V,	$V_{CC} = 0 V,$	Other inputs at 0 V		0.8	1	
I	Bus input current	A or B inputs	$V_{IH} = -7 V$ ,	V <sub>CC</sub> = 5 V,	Other inputs at 0 V		-0.5	-0.8	mA
			$V_{IH} = -7 V$ ,	$V_{CC} = 0 V,$	Other inputs at 0 V		-0.4	-0.8	
IIН	High-level enable input of	urrent	V <sub>IH</sub> = 5 V					±20	μA
١ <sub>١L</sub>	Low-level enable input c	urrent	V <sub>IL</sub> = 0 V					-20	μΑ
los	Short-circuit output curre	ent	$V_{O} = 0$				-80	-120	mA
	Cumply summat		Outputs enabled,	IO = 0,	V <sub>ID</sub> = 5 V		11	20	
ICC	Supply current		Outputs disabled				0.9	1.4	mA

<sup>†</sup> All typical values are at  $V_{CC} = 5$  V and  $T_A = 25^{\circ}C$ .

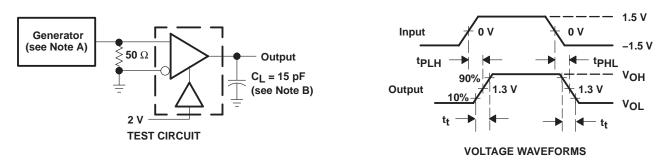
### switching characteristics, V<sub>CC</sub> = 5 V, C<sub>L</sub> = 15 pF, T<sub>A</sub> = 25°C

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
<sup>t</sup> PHL	Propagation delay time, high- to low-level output	$V_{ID} = -1.5 V$ to 1.5 V,	11	22	30	ns
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	See Figure 1	11	22	30	ns
<sup>t</sup> PZH	Output enable time to high level	See Figure 2		17	30	ns
t <sub>PZL</sub>	Output enable time to low level	See Figure 3		18	30	ns
<sup>t</sup> PHZ	Output disable time from high level	See Figure 2		30	40	ns
t <sub>PLZ</sub>	Output disable time from low level	See Figure 3		23	30	ns
t <sub>sk(p)</sub>	Pulse skew ( tpHL - tpLH )	See Figure 2		4	6	ns
tt	Transition time	See Figure 1		3	10	ns

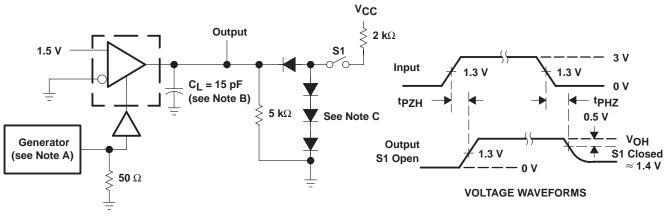


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### PARAMETER MEASUREMENT INFORMATION







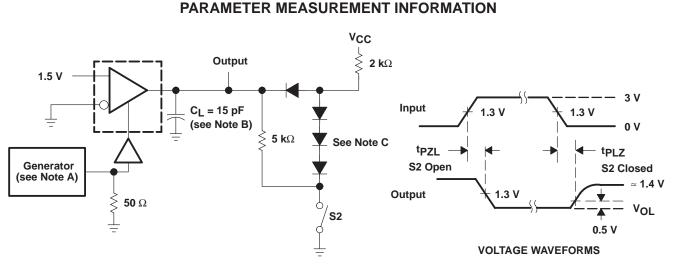
**TEST CIRCUIT** 

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%,  $t_{f} \le 6$  ns,  $t_{f} \le 6$  ns,  $Z_{O} = 50 \Omega$ .
  - B. CL includes probe and jig capacitance.
  - C. All diodes are 1N916 or equivalent.

### Figure 2. t<sub>PHZ</sub> and t<sub>PZH</sub> Test Circuit and Voltage Waveforms



SLLS171G – OCTOBER 1993 – REVISED MARCH2009

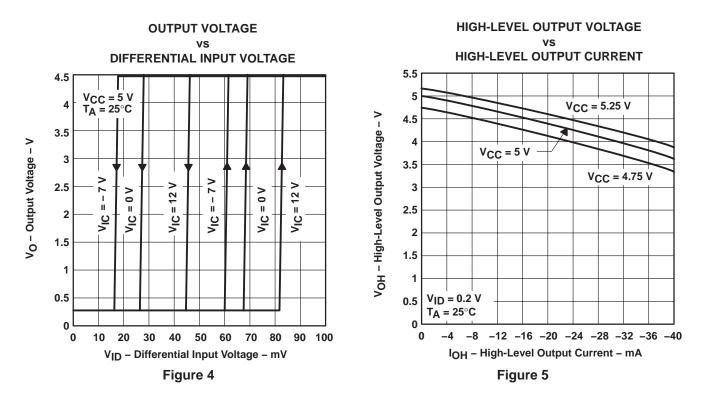


#### **TEST CIRCUIT**

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%,  $t_{f} \le 6$  ns,  $t_{f} \le 6$  ns,  $Z_{O} = 50 \Omega$ .
  - B. CL includes probe and jig capacitance.
  - C. All diodes are 1N916 or equivalent.

#### Figure 3. tPZL and tPLZ Test Circuit and Voltage Waveforms

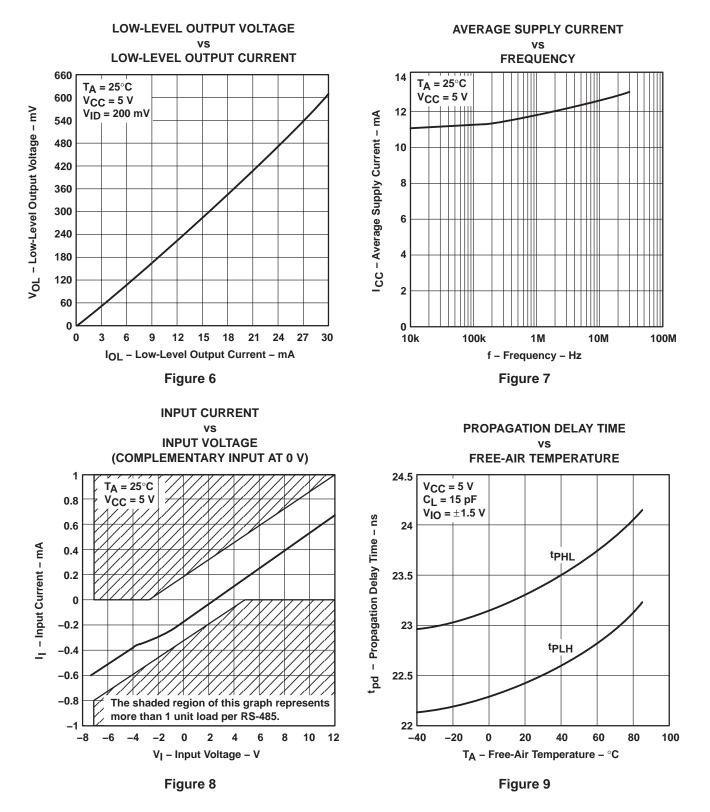






SLLS171G - OCTOBER 1993 - REVISED MARCH2009

### **TYPICAL CHARACTERISTICS**





17-Mar-2009

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65LBC175D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175DWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC175N	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65LBC175NE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC175D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC175DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC175DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC175DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC175N	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC175NE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



# PACKAGE OPTION ADDENDUM



<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN75LBC175 :

Military: SN55LBC175

NOTE: Qualified Version Definitions:

• Military - QML certified for Military and Defense Applications

# PACKAGE MATERIALS INFORMATION

www.ti.com

### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

TEXAS INSTRUMENTS





#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION	

\*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN65LBC175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN65LBC175DWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
SN75LBC175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75LBC175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC175DR	SOIC	D	16	2500	333.2	345.9	28.6
SN65LBC175DR	SOIC	D	16	2500	367.0	367.0	38.0
SN65LBC175DWR	SOIC	DW	16	2000	367.0	367.0	38.0
SN75LBC175DR	SOIC	D	16	2500	333.2	345.9	28.6
SN75LBC175DR	SOIC	D	16	2500	367.0	367.0	38.0

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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# D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AA.



# LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

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